TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74HC04AP, TC74HC04AF, TC74HC04AFN

#### **HEX INVERTER**

The TC74HC04A is a high speed CMOS INVERTER fabricated with silicon gate  $C^2MOS$  technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

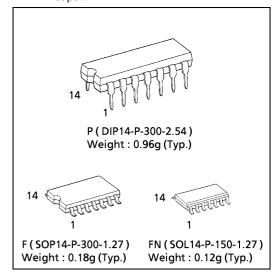
The internal circuit is composed of 3 stages, including buffered output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against satic discharge or transient excess voltage.

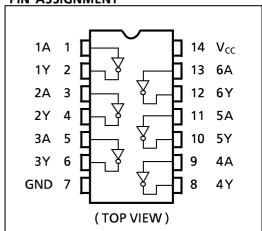
#### **FEATURES:**

- High Speed······ $t_{pd}$  = 6ns(typ.) at  $V_{CC}$  = 5V
- Low Power Dissipation ············· $I_{CC} = 1 \mu A(Max.)$  at  $Ta = 25 ^{\circ}C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (Min.)
- Output Drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance··· | I<sub>OH</sub> | = I<sub>OL</sub> = 4mA(Min.)
- Balanced Propagation Delays  $\cdots t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range ···· V<sub>CC</sub> (opr.) = 2V~6V
- Pin and Function Compatible with 74LS04

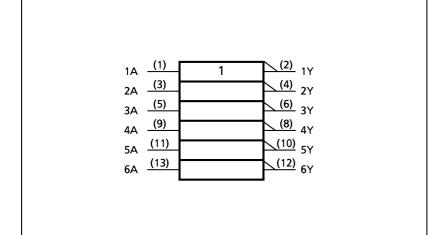
(Note) The JEDEC SOP (FN) is not available in Japan.



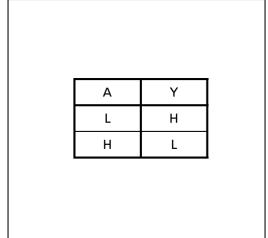
#### **PIN ASSIGNMENT**



# **IEC LOGIC SYMBOL**



#### TRUTH TABLE



## **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	-0.5~7	V
DC Input Voltage	V <sub>IN</sub>	$-0.5 \sim V_{CC} + 0.5$	V
DC Output Voltage	V <sub>OUT</sub>	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> / Ground Current	I <sub>cc</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

\*500mW in the range of Ta=  $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$ . From Ta=65°C to 85°C a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

#### **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V <sub>cc</sub>	2~6	V
Input Voltage	V <sub>IN</sub>	0~V <sub>CC</sub>	V
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

#### DC ELECTRICAL CHARACTERISTICS

PARAMETER SYMBOL		TEST CONDITION		V <sub>cc</sub>	Ta = 25°C		Ta = −40~85°C		UNIT	
				(v)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	VIH			2.0 4.5 6.0	1.50 3.15 4.20	_ _ _	_ _ _	1.50 3.15 4.20	_ _ _	٧
Low - Level Input Voltage	VIL			2.0 4.5 6.0	_ _ _	_ _ _	0.50 1.35 1.80	_ _ _	0.50 1.35 1.80	>
High - Level Output Voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	_ _ _	1.9 4.4 5.9	_ _ _	V
	V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -4 \text{ mA}$ $I_{OH} = -5.2 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	_	4.13 5.63	_		
Low - Level Output Voltage	V <sub>IN</sub> =	I <sub>OL</sub> = 20μΑ	2.0 4.5 6.0	_ _ _	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	\ \	
		V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 4  mA$ $I_{OL} = 5.2  mA$	4.5 6.0	_	0.17 0.18	0.26 0.26	_ _	0.33 0.33	
Input Leakage Current	I <sub>I N</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	_	±0.1	_	± 1.0	
Quiescent Supply Current	I <sub>cc</sub>	$V_{1N} = V_{C}$	<sub>C</sub> or GND	6.0	_	_	1.0	_	10.0	$\mu$ A

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AC ELECTRICAL CHARACTERISTICS ( $C_L = 15pF$ ,  $V_{CC} = 5V$ , Ta = 25°C, Input  $t_r = t_f = 6ns$ )

	•	2 1 7 66 7 7				
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>		_	4	8	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>		_	6	12	113

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50pF$ , Input  $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = −40~		0~85°C UNIT	
	3 T IVIDUL		$V_{CC}(V)$	MIN.	TYP.	MAX.	MIN.	MAX.	OWIT	
	t <sub>TLH</sub>		2.0	_	30	75	_	95		
Output Transition Time			4.5	_	8	15	_	19		
	t <sub>THL</sub>		6.0	_	7	13	_	16	nc	
	+		2.0	_	27	75	_	95	ns	
Propagation Delay Time	t <sub>pLH</sub>		4.5	_	9	15	_	19		
,,	t <sub>pHL</sub>		6.0	_	8	13	_	16		
Input Capacitance	C <sub>IN</sub>			_	5	10	_	10	pF	
Power Dissipation Capacitance	C <sub>PD</sub> (1)			-	20	_	_	_	рг	

Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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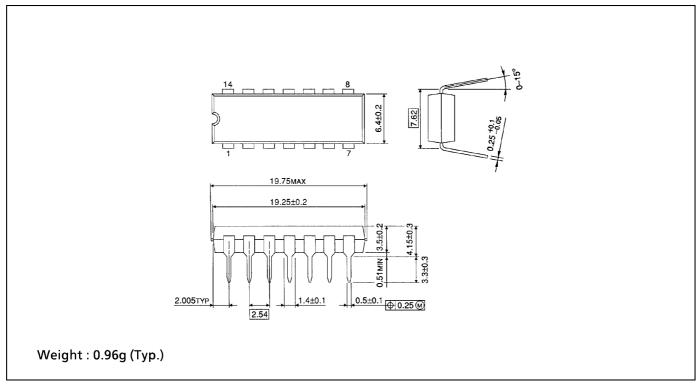
Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6$  (per Gate)

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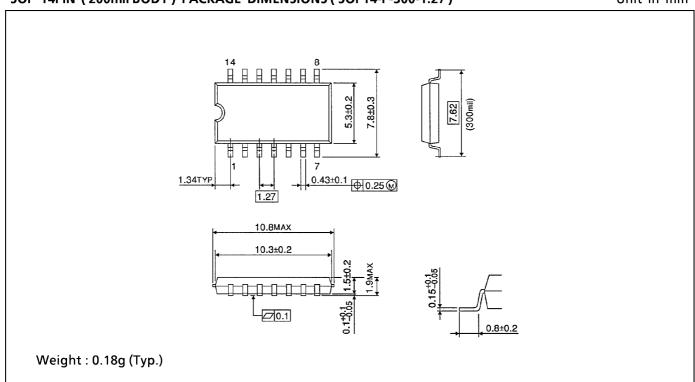
## DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)

Unit in mm



## SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

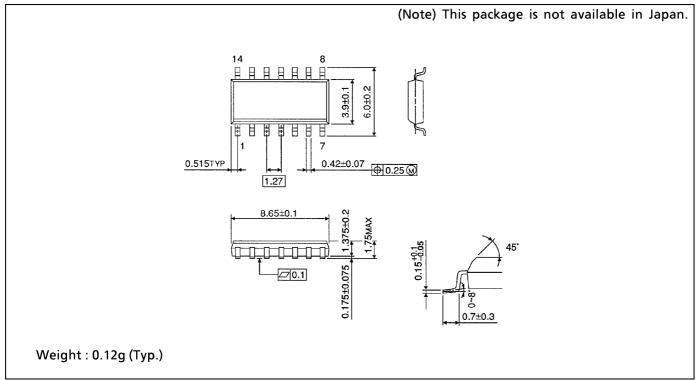
Unit in mm



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## SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)

Unit in mm



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